

ISL81483, ISL81487

1/8 Unit Load, 5V, Low Power, High Speed or Slew Rate Limited, RS-485/RS-422 Transceivers

FN6050
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These Renesas RS-485/RS-422 devices are “fractional” Unit Load (UL), BiCMOS, 5V powered, single transceivers that meet both the RS-485 and RS-422 standards for balanced communication. Unlike competitive devices, this family is specified for 10% tolerance supplies (4.5V to 5.5V).

The [ISL81483](#) and [ISL81487](#) present a 1/8 unit load to the RS-485 bus, which allows up to 256 transceivers on the network for large node count systems (for example, process automation, remote meter reading systems). In a remote utility meter reading system, individual (apartments for example) utility meter readings are routed to a concentrator through an RS-485 network, so the high allowed node count minimizes the number of repeaters required to network all the meters. Data for all meters is then read out from the concentrator using a single access port, or a wireless link.

The slew rate limited driver on the ISL81483 reduces EMI, and minimizes reflections from improperly terminated transmission lines, or unterminated stubs in multidrop and multipoint applications. Data rates up to 250kbps are achievable with these devices.

Data rates up to 5Mbps are achievable by using the ISL81487, which features higher slew rates.

Receiver (Rx) inputs feature a “fail-safe if open” design, which ensures a logic high Rx output if Rx inputs are floating.

Driver (Tx) outputs are short-circuit protected, even for voltages exceeding the power supply voltage. Additionally, on-chip thermal shutdown circuitry disables the Tx outputs to prevent damage if power dissipation becomes excessive.

These half duplex devices multiplex the Rx inputs and Tx outputs to allow transceivers with Rx and Tx disable functions in 8 Ld packages.

Related Literature

For a full list of related documents, visit our website:

- [ISL81483](#), [ISL81487](#) product pages

Features

- Fractional unit load allows up to 256 devices on the bus
- Specified for 10% tolerance supplies
- Class 3 ESD protection (HBM) on all pins >7kV
- High data rate version (ISL81487) up to 5Mbps
- Slew rate limited version for error free data transmission (ISL81483) up to 250kbps
- Low current shutdown mode (except ISL81487) . . . 0.5µA
- Low quiescent supply current:
 - ISL81483 145µA (Max.)
 - ISL81487 420µA (Max.)
- -7V to +12V common-mode input voltage range
- Three state Rx and Tx outputs
- 30ns propagation delays, 5ns skew (ISL81487)
- Half duplex pinouts
- Operate from a single +5V supply (10% tolerance)
- Current limiting and thermal shutdown for driver overload protection
- Drop-in replacements for: MAX1483 (ISL81483); MAX1487, LMS1487 (ISL81487)
- Pb-free plus anneal available (RoHS compliant)

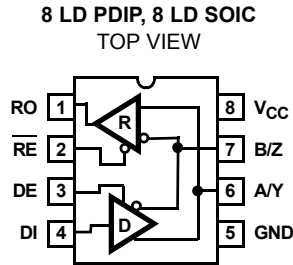
Applications

- High node count networks
- Automated utility meter reading systems
- Factory automation
- Security networks
- Building environmental control systems
- Industrial/process control networks

TABLE 1. SUMMARY OF FEATURES

PART NUMBER	HALF/FULL DUPLEX	NO. OF DEVICES ALLOWED ON BUS	DATA RATE (Mbps)	SLEW-RATE LIMITED?	RECEIVER/ DRIVER ENABLE?	QUIESCENT I _{CC} (µA)	LOW POWER SHUTDOWN?	PIN COUNT
ISL81483	Half	256	0.25	Yes	Yes	120	Yes	8
ISL81487	Half	256	5	No	Yes	350	No	8

Pinout



Truth Tables

TRANSMITTING				
INPUTS			OUTPUTS	
\overline{RE}	DE	DI	Z	Y
X	1	1	0	1
X	1	0	1	0
0	0	X	High-Z	High-Z
1	0	X	High-Z *	High-Z *

*Shutdown Mode for ISL81483 (see [Note 10](#))

RECEIVING			
INPUTS			OUTPUT
\overline{RE}	DE	A-B	RO
0	0	$\geq +0.2V$	1
0	0	$\leq -0.2V$	0
0	0	Inputs Open	1
1	0	X	High-Z *
1	1	X	High-Z

*Shutdown Mode for ISL81483 (see [Note 10](#))

Ordering Information

PART NUMBER (Notes 2, 3)	PART MARKING	TEMP. RANGE (°C)	TAPE AND REEL (UNITS) (Note 1)	PACKAGE (RoHS Compliant)	PKG. DWG. #
ISL81483IBZ	81483IBZ	-40 to +85	-	8 Ld SOIC	M8.15
ISL81483IBZ-T	81483IBZ	-40 to +85	2.5k	8 Ld SOIC	M8.15
ISL81483IPZ	81483IPZ	-40 to +85	-	8 Ld PDIP	E8.3
ISL81487IBZ	81487IBZ	-40 to +85	-	8 Ld SOIC	M8.15
ISL81487IBZ-T	81487IBZ	-40 to +85	2.5k	8 Ld SOIC	M8.15

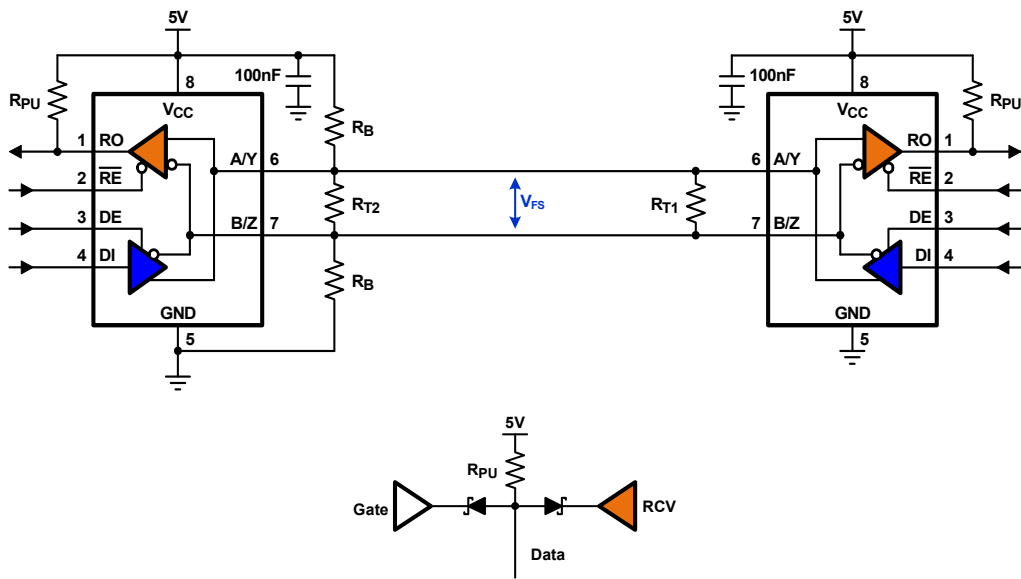
NOTES:

- Refer to [TB347](#) for details about reel specifications.
- Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- For Moisture Sensitivity Level (MSL), see the [ISL81483](#), [ISL81487](#) product information pages. For more information about MSL, see [TB363](#).

Pin Descriptions

PIN	FUNCTION
RO	Receiver output: RO is high if A > B by at least 0.2V; RO is low if A < B by 0.2V or more; RO = High if A and B are unconnected (floating).
\overline{RE}	Receiver output enable. RO is enabled when \overline{RE} is low; RO is high impedance when \overline{RE} is high.
DE	Driver output enable. The driver outputs, Y and Z, are enabled by bringing DE high. They are high impedance when DE is low.
DI	Driver input. A low on DI forces output Y low and output Z high. Similarly, a high on DI forces output Y high and output Z low.
GND	Ground connection.
A/Y	RS-485/422 level, noninverting receiver input and noninverting driver output. Pin is an input (A) if DE = 0; pin is an output (Y) if DE = 1.
B/Z	RS-485/422 level, inverting receiver input and inverting driver output. Pin is an input (B) if DE = 0; pin is an output (Z) if DE = 1.
V _{CC}	System power supply input (4.5V to 5.5V).

Typical Operating Circuits



To calculate the resistor values, refer to [TB509](#)

Absolute Maximum Ratings

V_{CC} to Ground	7V
Input Voltages	
DI, DE, RE	-0.5V to ($V_{CC} + 0.5V$)
Input/Output Voltages	
A/Y, B/Z	-8V to +12.5V
RO	-0.5V to ($V_{CC} + 0.5V$)
Short-Circuit Duration	
Y, Z	Continuous
ESD Rating	
HBM (Per MIL-STD-883, Method 3015.7)	>7kV

Operating Conditions

Temperature Range	-40°C to +85°C
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CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

NOTE:

4. θ_{JA} is measured with the component mounted on a low-effective thermal conductivity test board in free air. See [TB379](#) for details.

Thermal Information

Thermal Resistance (Typical, Note 4)	θ_{JA} (°C/W)
8 Ld SOIC Package	170
8 Ld PDIP Package*	140
Maximum Junction Temperature (Plastic Package)	+150°C
Maximum Storage Temperature Range	-65°C to +150°C
Maximum Lead Temperature (Soldering 10s)	+300°C (SOIC - Lead Tips Only)

*Pb-free PDIPs can be used for through hole wave solder processing only. They are not intended for use in Reflow solder processing applications.

Electrical Specifications Test conditions: $V_{CC} = 4.5V$ to $5.5V$; unless otherwise specified. Typicals are at $V_{CC} = 5V$, $T_A = +25^\circ C$, ([Note 5](#))

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNIT	
DC CHARACTERISTICS								
Driver Differential V_{OUT} (no load)	V_{OD1}		Full	-	-	V_{CC}	V	
Driver Differential V_{OUT} (with load)	V_{OD2}	R = 50Ω (RS-422), (Figure 1)	Full	2	3	-	V	
		R = 27Ω (RS-485), (Figure 1)	Full	1.5	2.3	5	V	
Change in Magnitude of Driver Differential V_{OUT} for Complementary Output States	ΔV_{OD}	R = 27Ω or 50Ω, (Figure 1)	Full	-	0.01	0.2	V	
Driver Common-Mode V_{OUT}	V_{OC}	R = 27Ω or 50Ω, (Figure 1)	Full	-	-	3	V	
Change in Magnitude of Driver Common-Mode V_{OUT} for Complementary Output States	ΔV_{OC}	R = 27Ω or 50Ω, (Figure 1)	Full	-	0.01	0.2	V	
Logic Input High Voltage	V_{IH}	DE, DI, \overline{RE}	Full	2	-	-	V	
Logic Input Low Voltage	V_{IL}	DE, DI, \overline{RE}	Full	-	-	0.8	V	
Logic Input Current	I_{IN1}	DE, DI, \overline{RE}	Full	-2	-	2	μA	
Input Current (A/Y, B/Z), (Note 13)	I_{IN2}	DE = 0V, $V_{CC} = 4.5$ to 5.5V	$V_{IN} = 12V$	Full	-	-	140	μA
			$V_{IN} = -7V$	Full	-	-	-120	μA
	I_{IN2}	DE = 0V, $V_{CC} = 0V$	$V_{IN} = 12V$	Full	-	-	180	μA
			$V_{IN} = -7V$	Full	-	-	-100	μA
Receiver Differential Threshold Voltage	V_{TH}	$-7V \leq V_{CM} \leq 12V$	Full	-0.2	-	0.2	V	
Receiver Input Hysteresis	ΔV_{TH}	$V_{CM} = 0V$	+25	-	70	-	mV	
Receiver Output High Voltage	V_{OH}	$I_O = -4mA$, $V_{ID} = 200mV$	Full	3.5	-	-	V	
Receiver Output Low Voltage	V_{OL}	$I_O = -4mA$, $V_{ID} = 200mV$	Full	-	-	0.4	V	
Three-State (high impedance) Receiver Output Current	I_{OZR}	$0.4V \leq V_O \leq 2.4V$	Full	-	-	±1	μA	
Receiver Input Resistance	R_{IN}	$-7V \leq V_{CM} \leq 12V$	ISL81483, ISL81487	Full	96	-	kΩ	

Electrical Specifications Test conditions: $V_{CC} = 4.5V$ to $5.5V$; unless otherwise specified. Typical values are at $V_{CC} = 5V$, $T_A = +25^\circ C$, (Note 5) (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNIT	
No-Load Supply Current, (Note 6)	I_{CC}	ISL81487, DI, $\overline{RE} = 0V$ or V_{CC}	DE = V_{CC}	Full	-	400	500	μA
			DE = 0V	Full	-	350	420	μA
		ISL81483, DI, $\overline{RE} = 0V$ or V_{CC}	DE = V_{CC}	Full	-	160	200	μA
			DE = 0V	Full	-	120	145	μA
Shutdown Supply Current	I_{SHDN}	(Note 10), DE = 0V, $\overline{RE} = V_{CC}$, DI = 0V or V_{CC}	Full	-	0.5	8	μA	
Driver Short-Circuit Current, $V_O =$ High or Low	I_{OSD1}	DE = V_{CC} , $-7V \leq V_Y$ or $V_Z \leq 12V$, (Note 7)	Full	35	-	250	mA	
Receiver Short-Circuit Current	I_{OSR}	$0V \leq V_O \leq V_{CC}$	Full	7	-	85	mA	
SWITCHING CHARACTERISTICS (ISL81487)								
Driver Input to Output Delay	t_{PLH}, t_{PHL}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	15	24	50	ns	
Driver Output Skew	t_{SKEW}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	-	2	10	ns	
Driver Differential Rise or Fall Time	t_R, t_F	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	3	12	25	ns	
Driver Enable to Output High	t_{ZH}	$C_L = 100pF$, SW = GND, (Figure 3)	Full	-	14	70	ns	
Driver Enable to Output Low	t_{ZL}	$C_L = 100pF$, SW = V_{CC} , (Figure 3)	Full	-	14	70	ns	
Driver Disable from Output High	t_{HZ}	$C_L = 15pF$, SW = GND, (Figure 3)	Full	-	44	70	ns	
Driver Disable from Output Low	t_{LZ}	$C_L = 15pF$, SW = V_{CC} , (Figure 3)	Full	-	21	70	ns	
Receiver Input to Output Delay	t_{PLH}, t_{PHL}	(Figure 4)	Full	30	90	150	ns	
Receiver Skew $t_{PLH} - t_{PHL}$	t_{SKD}	(Figure 4)	+25	-	5	-	ns	
Receiver Enable to Output High	t_{ZH}	$C_L = 15pF$, SW = GND, (Figure 5)	Full	-	9	50	ns	
Receiver Enable to Output Low	t_{ZL}	$C_L = 15pF$, SW = V_{CC} , (Figure 5)	Full	-	9	50	ns	
Receiver Disable from Output High	t_{HZ}	$C_L = 15pF$, SW = GND, (Figure 5)	Full	-	9	50	ns	
Receiver Disable from Output Low	t_{LZ}	$C_L = 15pF$, SW = V_{CC} , (Figure 5)	Full	-	9	50	ns	
Maximum Data Rate	f_{MAX}		Full	5	-	-	Mbps	
SWITCHING CHARACTERISTICS (ISL81483)								
Driver Input to Output Delay	t_{PLH}, t_{PHL}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	250	650	2000	ns	
Driver Output Skew	t_{SKEW}	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	-	160	800	ns	
Driver Differential Rise or Fall Time	t_R, t_F	$R_{DIFF} = 54\Omega$, $C_L = 100pF$, (Figure 2)	Full	250	900	2000	ns	
Driver Enable to Output High	t_{ZH}	$C_L = 100pF$, SW = GND, (Figure 3, Note 8)	Full	250	1000	2000	ns	
Driver Enable to Output Low	t_{ZL}	$C_L = 100pF$, SW = V_{CC} , (Figure 3, Note 8)	Full	250	860	2000	ns	
Driver Disable from Output High	t_{HZ}	$C_L = 15pF$, SW = GND, (Figure 3)	Full	300	660	3000	ns	
Driver Disable from Output Low	t_{LZ}	$C_L = 15pF$, SW = V_{CC} , (Figure 3)	Full	300	640	3000	ns	
Receiver Input to Output Delay	t_{PLH}, t_{PHL}	(Figure 4)	Full	250	500	2000	ns	
Receiver Skew $t_{PLH} - t_{PHL}$	t_{SKD}	(Figure 4)	+25	-	60	-	ns	
Receiver Enable to Output High	t_{ZH}	$C_L = 15pF$, SW = GND, (Figure 5, Note 9)	Full	-	10	50	ns	
Receiver Enable to Output Low	t_{ZL}	$C_L = 15pF$, SW = V_{CC} , (Figure 5, Note 9)	Full	-	10	50	ns	
Receiver Disable from Output High	t_{HZ}	$C_L = 15pF$, SW = GND, (Figure 5)	Full	-	10	50	ns	
Receiver Disable from Output Low	t_{LZ}	$C_L = 15pF$, SW = V_{CC} , (Figure 5)	Full	-	10	50	ns	
Maximum Data Rate	f_{MAX}		Full	250	-	-	kbps	
Time to Shutdown	t_{SHDN}	(Note 10)	Full	50	120	600	ns	
Driver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$C_L = 100pF$, SW = GND, (Figure 3, Notes 10, 11)	Full	-	1000	2000	ns	

Electrical Specifications Test conditions: $V_{CC} = 4.5V$ to $5.5V$; unless otherwise specified. Typicals are at $V_{CC} = 5V$, $T_A = +25^{\circ}C$, (Note 5) (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN	TYP	MAX	UNIT
Driver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$C_L = 100pF, SW = V_{CC}$, (Figure 3, Notes 10, 11)	Full	-	1000	2000	ns
Receiver Enable from Shutdown to Output High	$t_{ZH}(SHDN)$	$C_L = 15pF, SW = GND$, (Figure 5, Notes 10, 12)	Full	-	800	2500	ns
Receiver Enable from Shutdown to Output Low	$t_{ZL}(SHDN)$	$C_L = 15pF, SW = V_{CC}$, (Figure 5, Notes 10, 12)	Full	-	800	2500	ns

NOTES:

- All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified.
- Supply current specification is valid for loaded drivers when $DE = 0V$.
- Applies to peak current. See "Typical Performance Curves" on page 9 for more information.
- When testing the ISL81483, keep $\overline{RE} = 0$ to prevent the device from entering SHDN.
- When testing the ISL81483, the \overline{RE} signal high time must be short enough (typically $<200ns$) to prevent the device from entering SHDN.
- The ISL81483 is put into shutdown by bringing \overline{RE} high and DE low. If the inputs are in this state for less than $50ns$, the parts are ensured not to enter shutdown. If the inputs are in this state for at least $600ns$, the parts are ensured to have entered shutdown. See "Low Power Shutdown Mode (Excluding ISL81487)" on page 9.
- Keep $\overline{RE} = V_{CC}$, and set the DE signal low time $>600ns$ to ensure that the device enters SHDN.
- Set the \overline{RE} signal high time $>600ns$ to ensure that the device enters SHDN.
- Devices meeting these limits are denoted as "1/8 unit load (1/8 UL)" transceivers. The RS-485 standard allows up to 32 Unit Loads on the bus, so there can be 256 1/8 UL devices on a bus.

Test Circuits and Waveforms

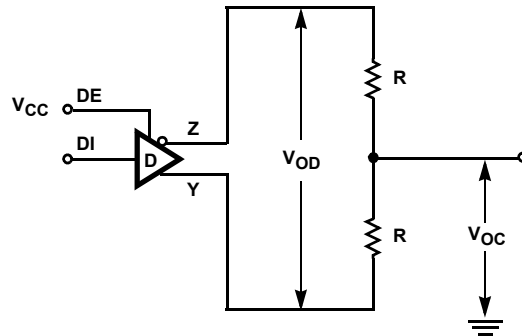


FIGURE 1. DRIVER V_{OD} AND V_{OC}

Test Circuits and Waveforms (Continued)

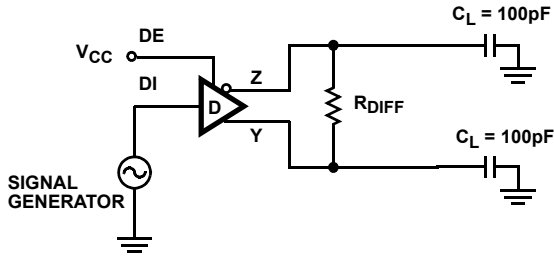
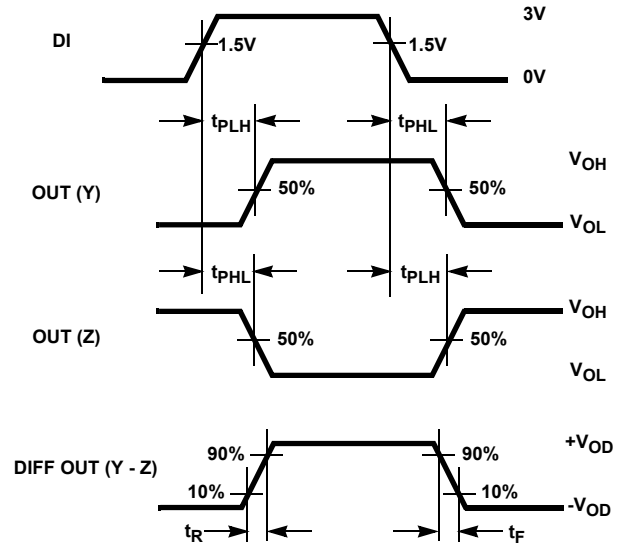


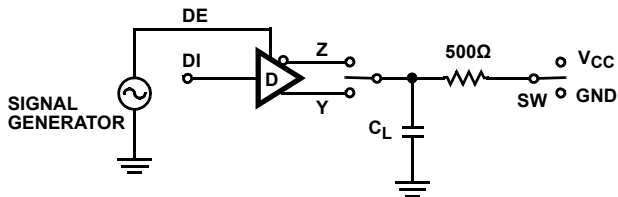
FIGURE 2A. TEST CIRCUIT



$$\text{SKEW} = |t_{PLH}(Y \text{ or } Z) - t_{PHL}(Z \text{ or } Y)|$$

FIGURE 2B. MEASUREMENT POINTS

FIGURE 2. DRIVER PROPAGATION DELAY AND DIFFERENTIAL TRANSITION TIMES



(SHDN) for ISL81483 only.

PARAMETER	OUTPUT	RE	DI	SW	CL (pF)
t_{HZ}	Y/Z	X	1/0	GND	15
t_{LZ}	Y/Z	X	0/1	VCC	15
t_{ZH}	Y/Z	0 (Note 8)	1/0	GND	100
t_{ZL}	Y/Z	0 (Note 8)	0/1	VCC	100
$t_{ZH}(\text{SHDN})$	Y/Z	1 (Note 10)	1/0	GND	100
$t_{ZL}(\text{SHDN})$	Y/Z	1 (Note 10)	0/1	VCC	100

FIGURE 3A. TEST CIRCUIT

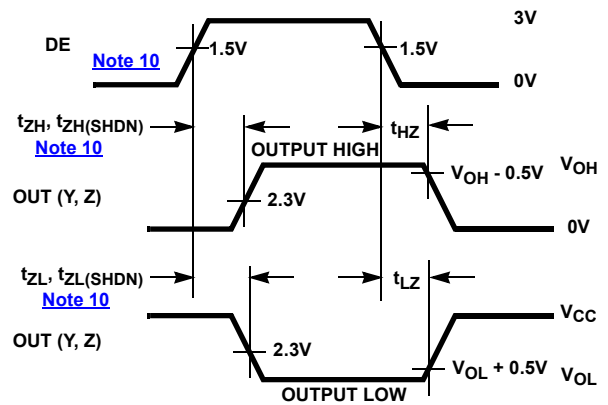


FIGURE 3B. MEASUREMENT POINTS

FIGURE 3. DRIVER ENABLE AND DISABLE TIMES

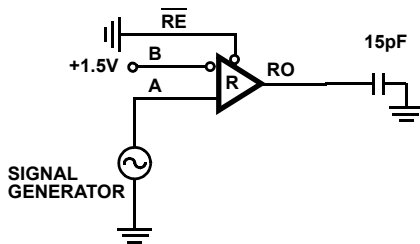


FIGURE 4A. TEST CIRCUIT

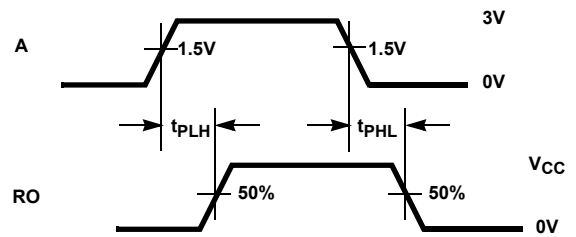
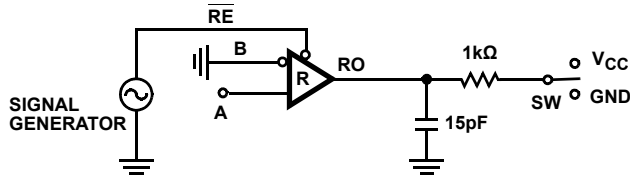


FIGURE 4B. MEASUREMENT POINTS

FIGURE 4. RECEIVER PROPAGATION DELAY

Test Circuits and Waveforms (Continued)



(SHDN) for ISL81483 only.

PARAMETER	DE	A	SW
t_{HZ}	0	+1.5V	GND
t_{LZ}	0	-1.5V	V _{CC}
t_{ZH} (Note 6)	0	+1.5V	GND
t_{ZL} (Note 6)	0	-1.5V	V _{CC}
$t_{ZH}(SHDN)$ (Note 7)	0	+1.5V	GND
$t_{ZL}(SHDN)$ (Note 7)	0	-1.5V	V _{CC}

FIGURE 5A. TEST CIRCUIT

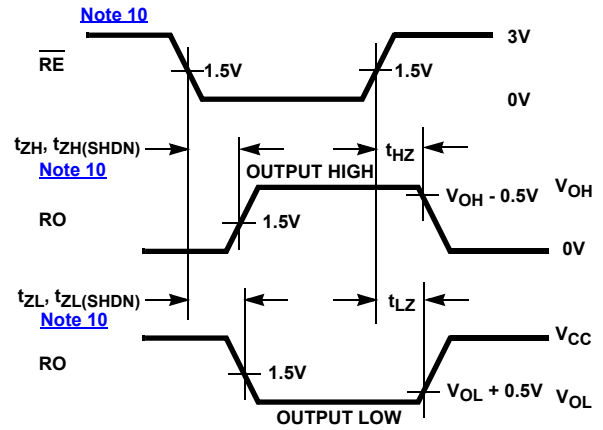


FIGURE 5B. MEASUREMENT POINTS

FIGURE 5. RECEIVER ENABLE AND DISABLE TIMES

Application Information

RS-485 and RS-422 are differential (balanced) data transmission standards for use in long haul or noisy environments. RS-422 is a subset of RS-485, so RS-485 transceivers are also RS-422 compliant. RS-422 is a point-to-multipoint (multidrop) standard that allows only one driver and up to 10 receivers on each bus assuming one unit load devices. RS-485 is a true multipoint standard that allows up to 32 one unit load devices (any combination of drivers and receivers) on each bus. To allow for multipoint operation, the RS-485 specification requires that drivers must handle bus contention without sustaining any damage.

Another important advantage of RS-485 is the extended Common-Mode Range (CMR). The CMR specifies that the driver outputs and receiver inputs withstand signals that range from +12V to -7V. RS-422 and RS-485 are intended for runs as long as 4000ft, so the wide CMR is necessary to handle ground potential differences and voltages induced in the cable by external fields.

Receiver Features

These devices use a differential input receiver for maximum noise immunity and common-mode rejection. Input sensitivity is $\pm 200mV$, as required by the RS-422 and RS-485 specifications.

Receiver input resistance of 96k Ω surpasses the RS-422 specification of 4k Ω and is eight times the RS-485 “Unit Load (UL)” requirement of 12k Ω minimum. The products are known as “one-eighth UL” transceivers, and there can be up to 256 of the devices on a network while still complying with the RS-485 loading specification.

Receiver inputs function with common-mode voltages as great as $\pm 7V$ outside the power supplies (such as +12V and

-7V), making them ideal for long networks in which induced voltages are a realistic concern.

All the receivers include a “fail-safe if open” function that ensures a high level receiver output if the receiver inputs are unconnected (floating).

Receivers easily meet the data rates supported by the corresponding driver, and receiver outputs are three-statable using the active low \overline{RE} input.

Driver Features

The RS-485 and RS-422 drivers are differential output devices that deliver at least 1.5V across a 54 Ω load (RS-485), and at least 2V across a 100 Ω load (RS-422). The drivers feature a low propagation delay skew to maximize bit width and to minimize EMI.

Driver outputs are tri-statable using the active high DE input.

The ISL81483 driver outputs are slew rate limited to minimize EMI and to minimize reflections in unterminated or improperly terminated networks. Data rate on these slew rate limited versions is a maximum of 250kbps. ISL81487 drivers are not limited, so faster output transition times allow data rates of at least 5Mbps.

Data Rate, Cables, and Terminations

RS-485 and RS-422 are intended for network lengths up to 4000ft, but the maximum system data rate decreases as the transmission length increases. Devices operating at 5Mbps are limited to lengths less than a few hundred feet, while the 250kbps versions can operate at full data rates with lengths in excess of 1000ft.

Twisted pair cable is the cable of choice for the RS-485 and RS-422 networks. Twisted pair cables pick up noise and other electromagnetically induced voltages as

common-mode signals, which are effectively rejected by the differential receivers in these ICs.

To minimize reflections, proper termination is imperative when using the 5Mbps device. Short networks using the 250kbps versions need not be terminated, but terminations are recommended unless power dissipation is an overriding concern.

In point-to-point or point-to-multipoint (single driver on bus) networks, terminate the main cable in its characteristic impedance (typically 120Ω) at the end farthest from the driver. In multi-receiver applications, keep stubs connecting receivers to the main cable as short as possible. In multipoint (multi-driver) systems, terminate the main cable in its characteristic impedance at both ends. Keep stubs that are connecting a transceiver to the main cable as short as possible.

Built-In Driver Overload Protection

As stated previously, the RS-485 specification requires that drivers survive worst case bus contentions undamaged. These devices meet this requirement through the driver output short-circuit current limits and on-chip thermal shutdown circuitry.

The driver output stages incorporate short-circuit current limiting circuitry that ensures that the output current never exceeds the RS-485 specification, even at the common-mode voltage range extremes. Additionally, these

devices use a foldback circuit that reduces the short-circuit current and the power dissipation when the contending voltage exceeds either supply.

In the event of a major short-circuit condition, the devices' thermal shutdown feature disables the drivers whenever the die temperature becomes excessive. This eliminates the power dissipation allowing the die to cool. The drivers automatically re-enable after the die temperature drops about 15°. If the contention persists, the thermal shutdown/re-enable cycle repeats until the fault is cleared. Receivers stay operational during thermal shutdown.

Low Power Shutdown Mode (Excluding ISL81487)

These CMOS transceivers all use a fraction of the power required by their bipolar counterparts. However, the ISL81483 includes a shutdown feature that reduces the already low quiescent I_{CC} to a 500nA trickle. They enter shutdown whenever the receiver and driver are **simultaneously** disabled (RE = V_{CC} and DE = GND) for a period of at least 600ns. Disabling both the driver and the receiver for less than 50ns ensures that shutdown is not entered.

Note that receiver and driver enable times increase when enabling from shutdown. Refer to [Notes 5](#) through [13](#) on [page 6](#) at the end of the Electrical Specification table for more information.

Typical Performance Curves V_{CC} = 5V, T_A = +25°C, ISL81483 and ISL81487; unless otherwise specified

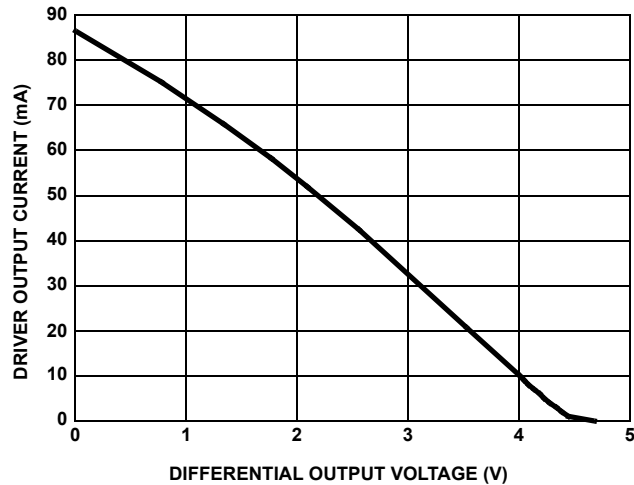


FIGURE 6. DRIVER OUTPUT CURRENT vs DIFFERENTIAL OUTPUT VOLTAGE

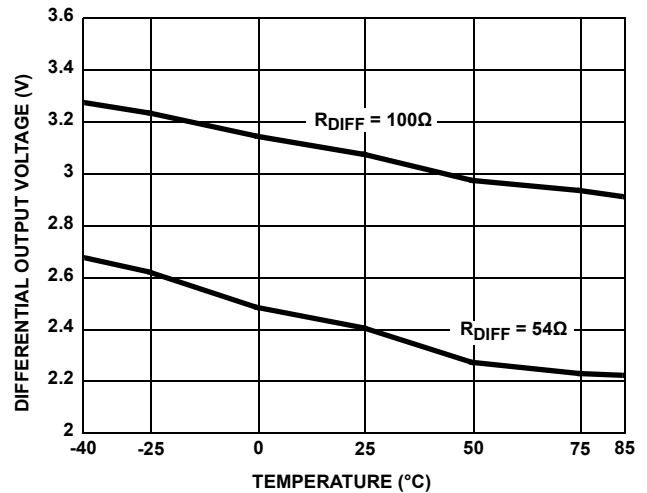


FIGURE 7. DRIVER DIFFERENTIAL OUTPUT VOLTAGE vs TEMPERATURE

Typical Performance Curves $V_{CC} = 5V, T_A = +25^{\circ}C$, ISL81483 and ISL81487; unless otherwise specified (Continued)

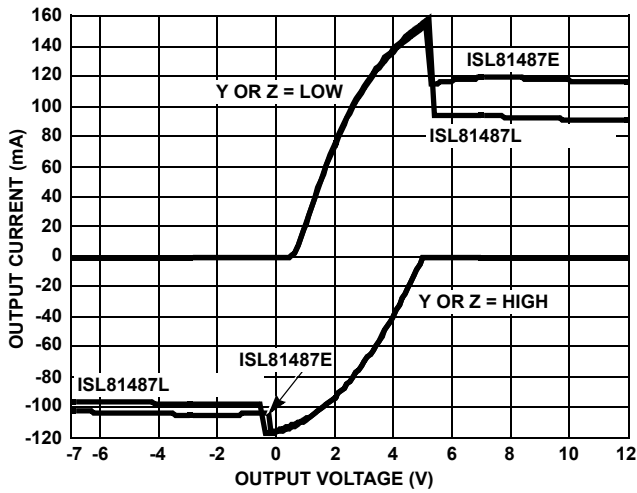


FIGURE 8. DRIVER OUTPUT CURRENT vs SHORT CIRCUIT VOLTAGE

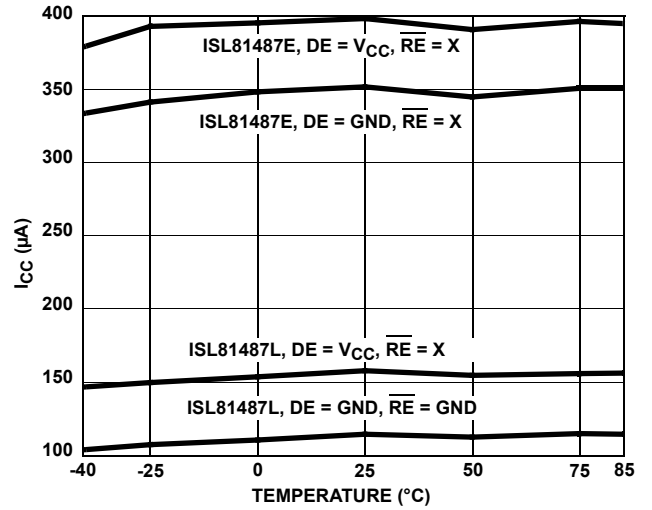


FIGURE 9. SUPPLY CURRENT vs TEMPERATURE

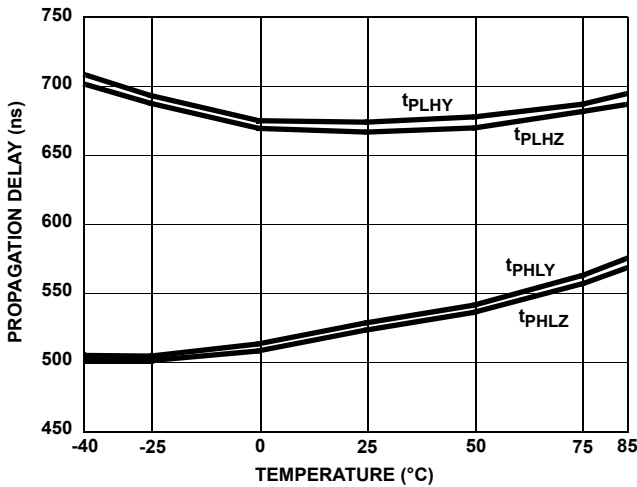


FIGURE 10. DRIVER PROPAGATION DELAY vs TEMPERATURE (ISL81483)

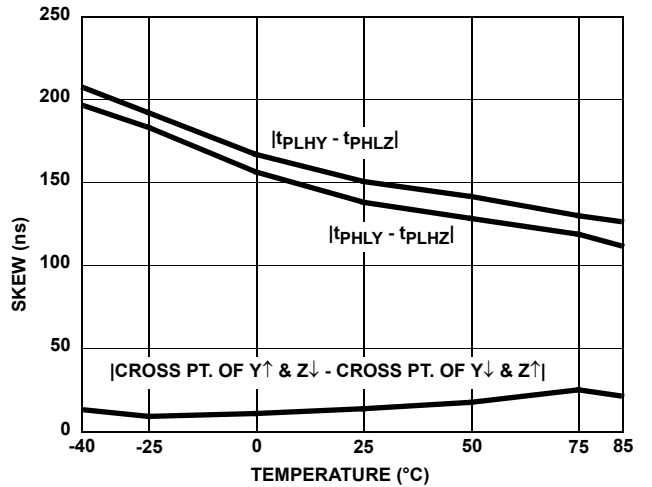


FIGURE 11. DRIVER SKEW vs TEMPERATURE (ISL81483)

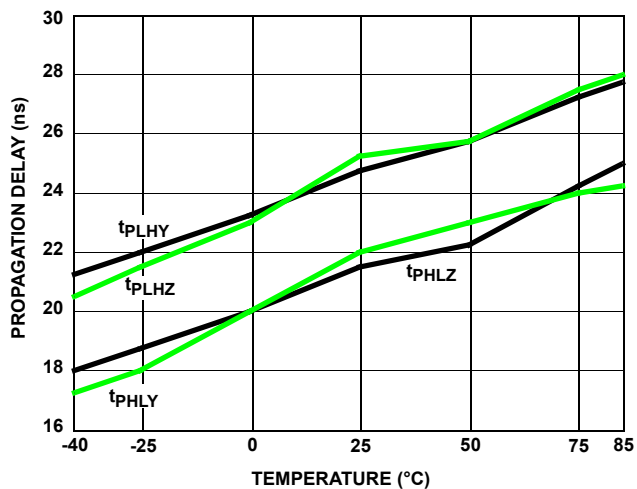


FIGURE 12. DRIVER PROPAGATION DELAY vs TEMPERATURE (ISL81487)

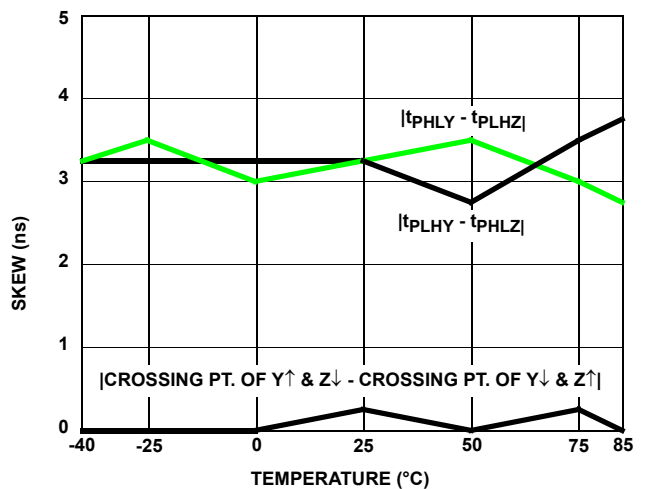


FIGURE 13. DRIVER SKEW vs TEMPERATURE (ISL81487)

Typical Performance Curves $V_{CC} = 5V$, $T_A = +25^\circ C$, ISL81483 and ISL81487; unless otherwise specified (Continued)

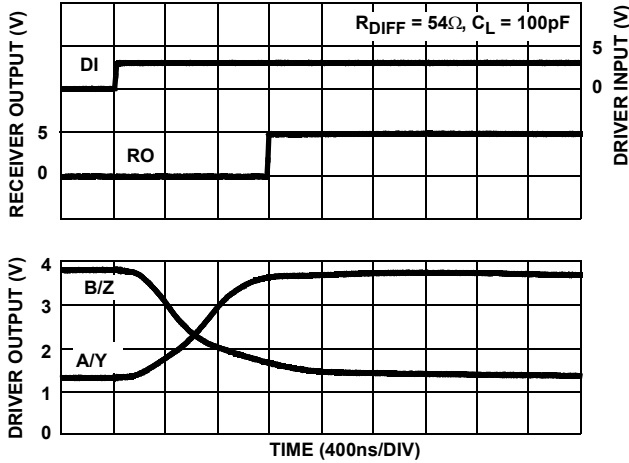


FIGURE 14. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL81483)

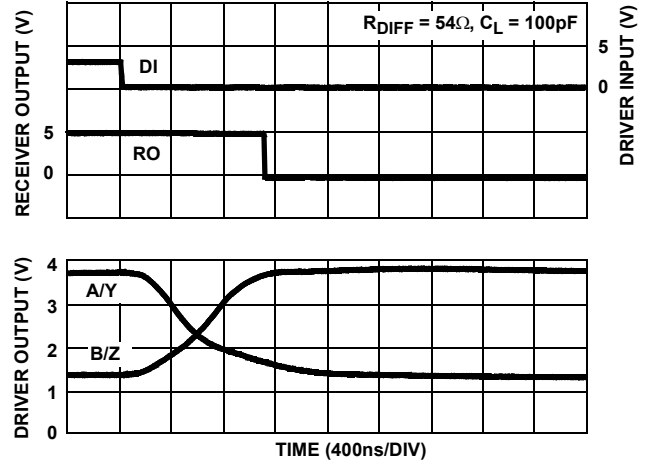


FIGURE 15. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL81483)

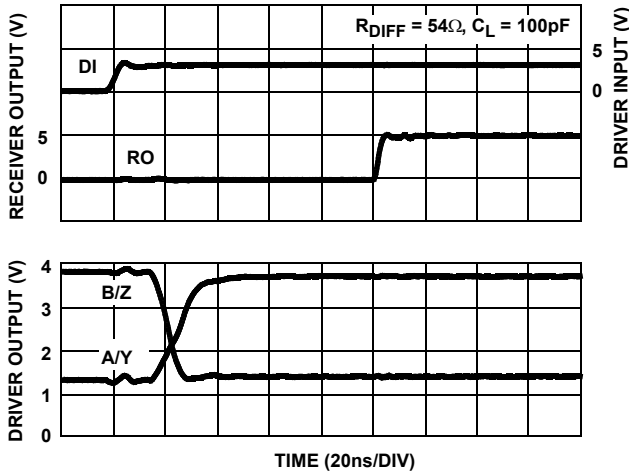


FIGURE 16. DRIVER AND RECEIVER WAVEFORMS, LOW TO HIGH (ISL81487)

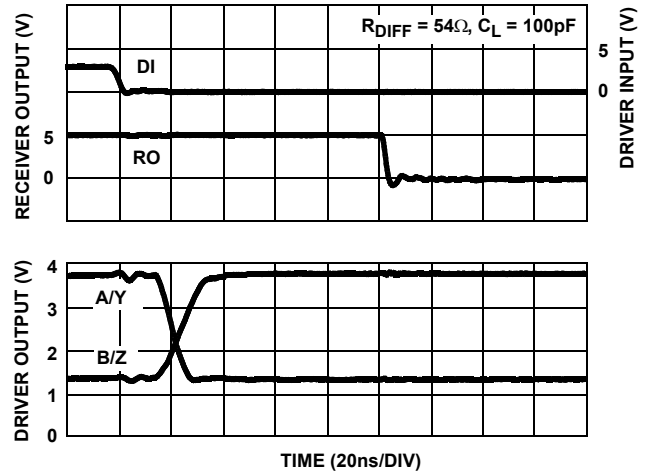


FIGURE 17. DRIVER AND RECEIVER WAVEFORMS, HIGH TO LOW (ISL81487)

Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

GND

TRANSISTOR COUNT:

518

PROCESS:

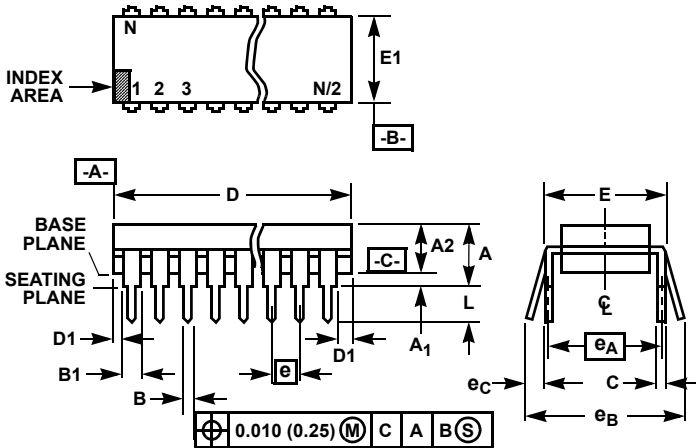
Si Gate CMOS

Revision History The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to the web to make sure that you have the latest revision.

DATE	REVISION	CHANGE
Sep 6, 2018	FN6050.9	Added Related Literature section. Removed ISL8487 information from datasheet. Updated Typical Operating Circuits on page 3. Updated the Ordering Information table by adding tape and reel information, adding Notes 1 and 3. Removed Note 11. Removed About Intersil section and updated disclaimer.
March 14, 2016	FN6050.8	Added Rev History and About Intersil Verbiage. Updated "Ordering Information" table on page 2. Updated M8.15 to current revision. POD revision changes are as follows: Note 1 "1982" to "1994" Changed in Typical Recommended Land Pattern the following: 2.41(0.095) to 2.20(0.087) 0.76 (0.030) to 0.60(0.023) 0.200 to 5.20(0.205) Updated to new POD format by removing table and moving dimensions onto drawing and adding land pattern.

Package Outline Drawings

For the most recent package outline drawing, see [E8.3](#).



**E8.3 (JEDEC MS-001-BA ISSUE D)
8 LEAD DUAL-IN-LINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
B	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
C	0.008	0.014	0.204	0.355	-
D	0.355	0.400	9.01	10.16	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		6
eB	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	8		8		9

NOTES:

14. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
15. Dimensioning and tolerancing per ANSI Y14.5M-1982.
16. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
17. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
18. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
19. E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
20. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
21. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
22. N is the maximum number of terminal positions.
23. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

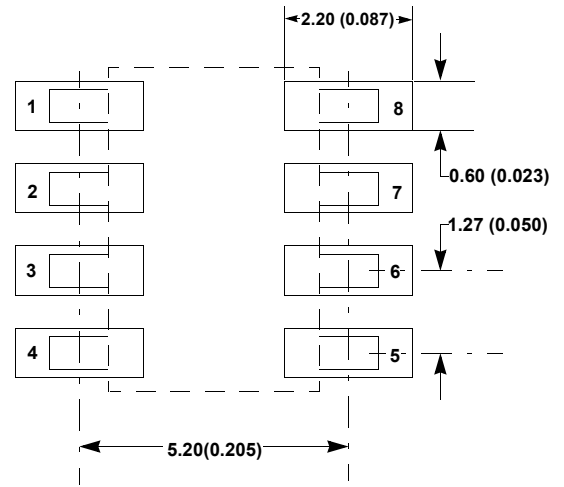
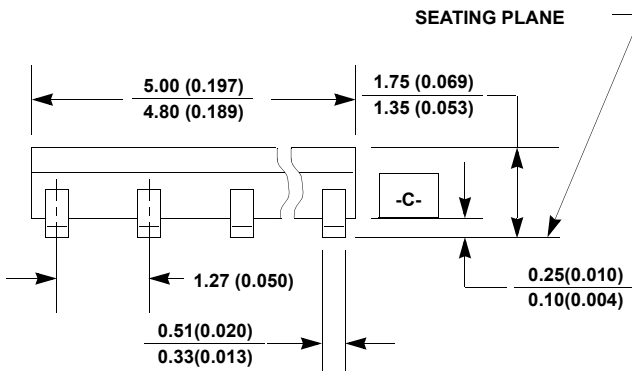
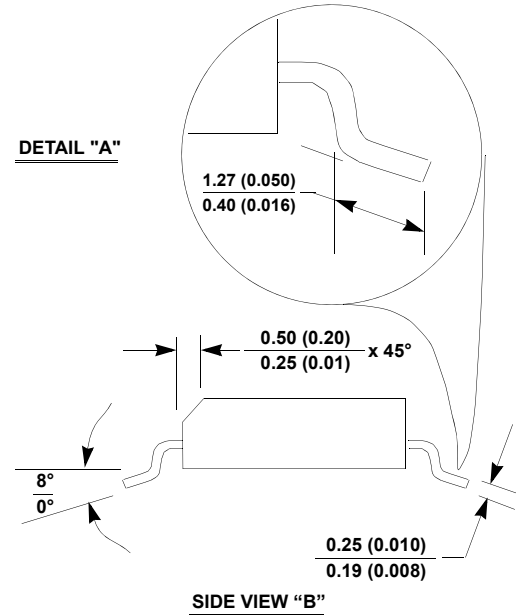
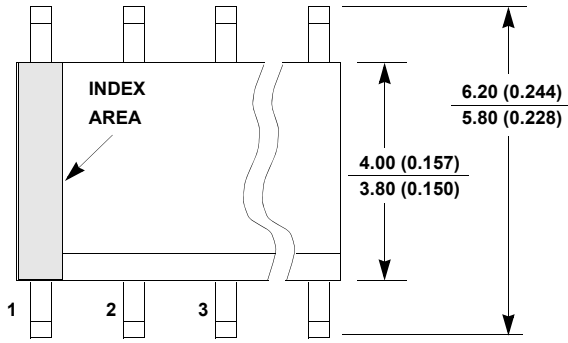
Rev. 0 12/93

M8.15

8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

Rev 4, 1/12

For the most recent package outline drawing, see [M8.15](#).



NOTES:

24. Dimensioning and tolerancing per ANSI Y14.5M-1994.
25. Package length does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
26. Package width does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
27. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
28. Terminal numbers are shown for reference only.
29. The lead width as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
30. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.
31. This outline conforms to JEDEC publication MS-012-AA ISSUE C.

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